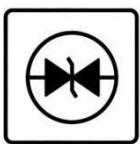




ESD



TVS



TSS



MOV



GDT



PLED

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## LM358ADT-MS

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### Product specification

## GENERAL DESCRIPTION

The LM358ADT-MS consists of two independent, high gain and internally frequency compensated operational amplifiers, they are specifically designed to operate from a single power supply. Operation from split power supply is also possible and the low power supply current drain is independent of the magnitude of the power supply voltages. Typical applications include transducer amplifiers, DC gain blocks and most conventional operational amplifier circuits.

The LM358ADT-MS is available in SOP-8 package.

## FEATURES

- Internally Frequency Compensated for Unity Gain
- Large Voltage Gain: 100dB (Typical)
- Low Input Bias Current: 20nA (Typical)
- Low Input Offset Voltage: 2mV (Typical)
- Low Supply Current: 0.5mA (Typical)
- Wide Power Supply Voltage:
  - Single Supply: 3V to 36V
  - Dual Supplies:  $\pm 1.5V$  to  $\pm 18V$
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V to  $V_{CC} - 1.5V$
- Lead-Free Packages: SOP-8

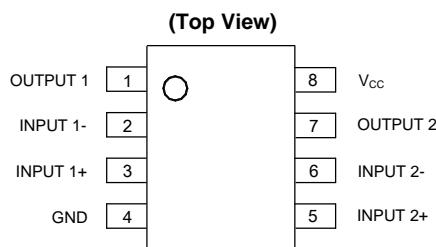
## Applications

- Battery Charger
- Cordless Telephone
- Switching Power Supply

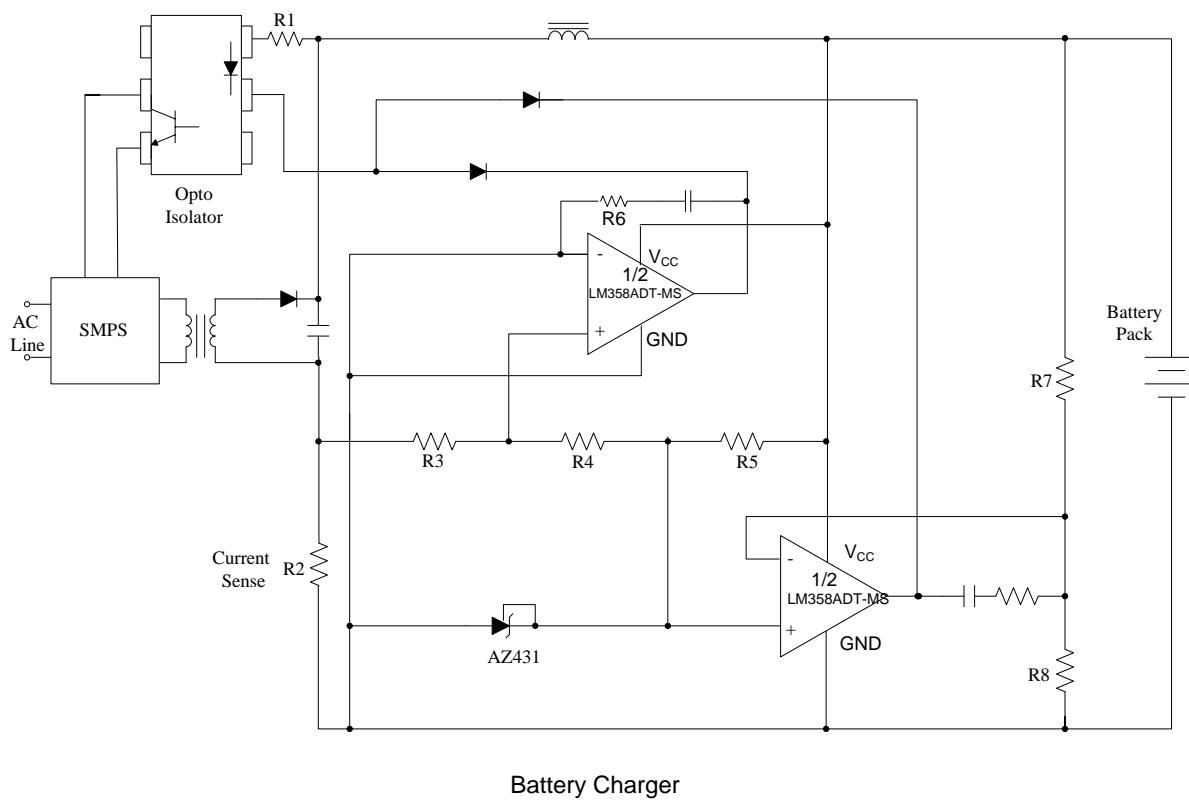
## Reference News

Type No	SOP-8	MARKING
LM358ADT-MS		

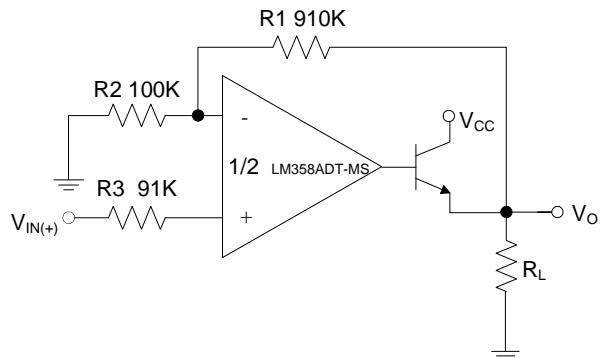
## Pin Assignments



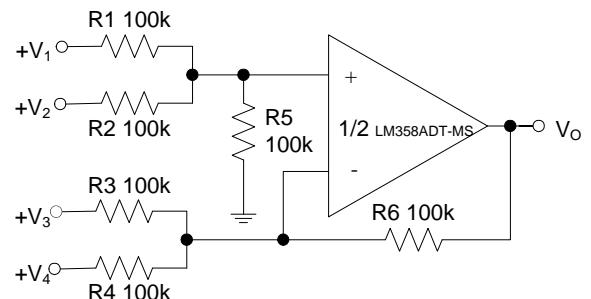
## Typical Applications Circuit



Battery Charger

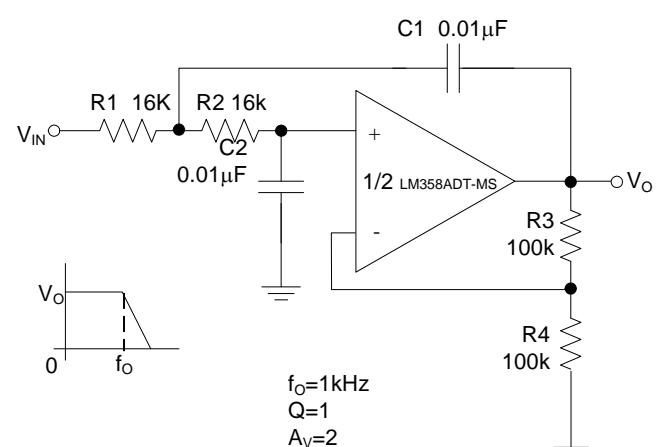
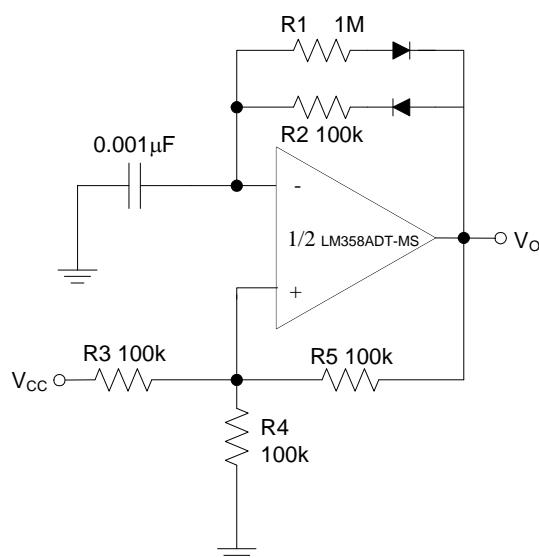
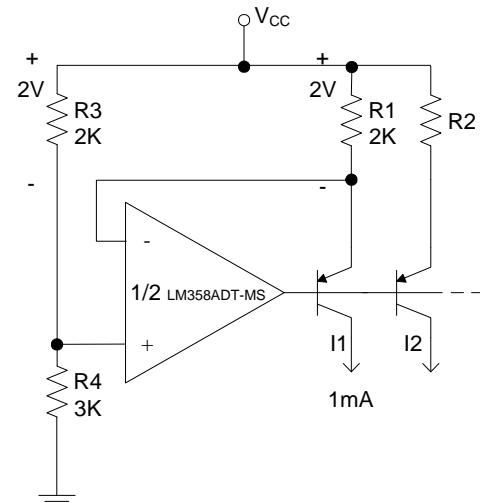
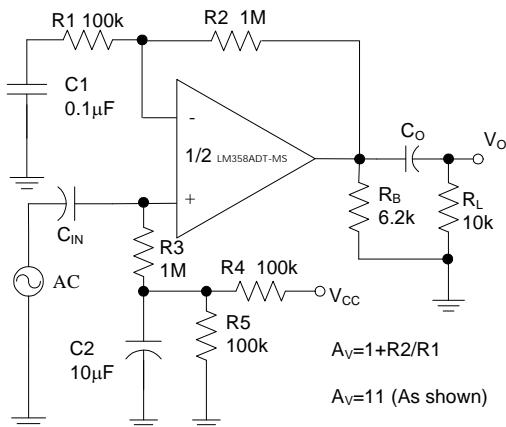


Power Amplifier

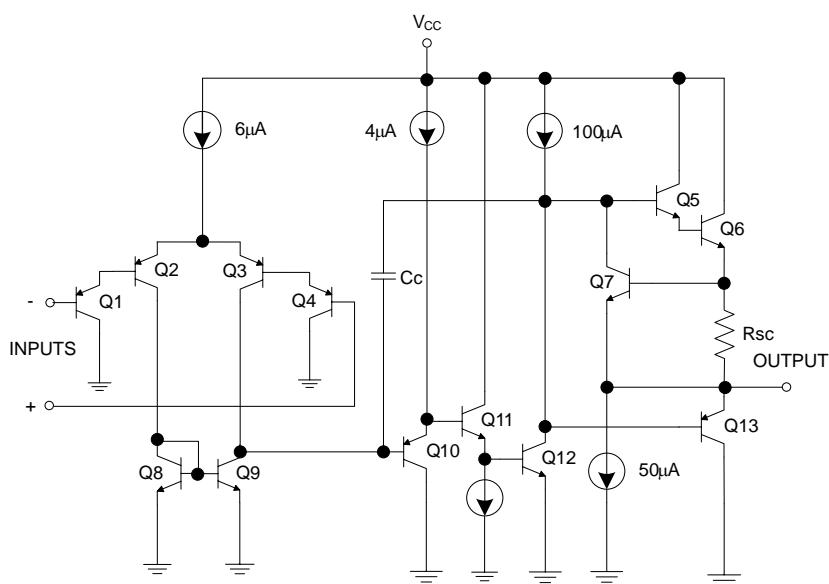


DC Summing Amplifier

**Typical Applications Circuit (Cont.)**



## Functional Block Diagram



## Absolute Maximum Ratings (Notes 1 & 2)

Symbol	Parameter	Rating	Unit
V <sub>CC</sub>	Power Supply Voltage	40	V
V <sub>ID</sub>	Differential Input Voltage	40	V
V <sub>IC</sub>	Input Voltage	-0.3 to 40	V
P <sub>D</sub>	Power Dissipation (T <sub>A</sub> = +25°C)	500	mW
T <sub>J</sub>	Operating Junction Temperature	+150	°C
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>LEAD</sub>	Lead Temperature (Soldering, 10 Seconds)	+260	°C

Notes: 1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.  
 2. ESD sensitivity.

## Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	3	36	V
T <sub>A</sub>	Ambient Operating Temperature Range	-40	+85	°C

**Electrical Characteristics** (Limits in standard typeface are for  $T_A = +25^\circ\text{C}$ , bold typeface applies over  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  (Note 6),  $V_{CC} = 5\text{V}$ ,  $GND = 0\text{V}$ , unless otherwise specified.)

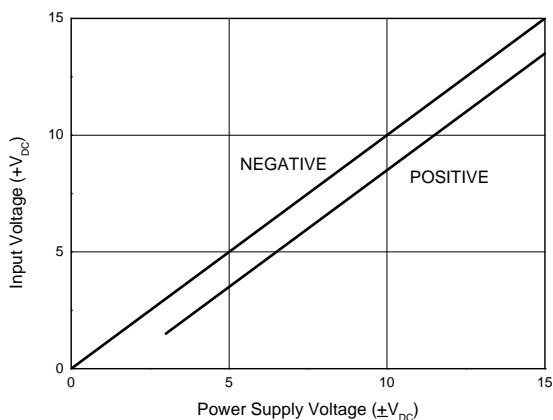
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IO}$	Input Offset Voltage	$V_O = 1.4\text{V}$ , $R_S = 0\Omega$ , $V_{CC} = 5\text{V}$ to $30\text{V}$	—	2	5	mV
			—	—	7	
$\Delta V_{IO}/\Delta T$	Average Temperature Coefficient of Input Offset Voltage	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	—	7	—	$\mu\text{V}/^\circ\text{C}$
$I_{BIAS}$	Input Bias Current	$I_{IN+}$ or $I_{IN-}$ , $V_{CM} = 0\text{V}$	—	20	200	nA
			—	—	200	
$I_{IO}$	Input Offset Current	$I_{IN+} - I_{IN-}$ , $V_{CM} = 0\text{V}$	—	5	30	nA
			—	—	100	
$V_{IR}$	Input Common Mode Voltage Range (Note 2)	$V_{CC} = 30\text{V}$	0	—	$V_{CC} - 1.5$	V
$I_{CC}$	Supply Current	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ , $R_L = \infty$ , $V_{CC} = 30\text{V}$	—	0.7	2	mA
		$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ , $R_L = \infty$ , $V_{CC} = 5\text{V}$	—	0.5	1.2	
$G_V$	Large Signal Voltage Gain	$V_{CC} = 15\text{V}$ , $V_O = 1\text{V}$ to $11\text{V}$ , $R_L \geq 2\text{k}\Omega$	85	100	—	dB
			80	—	—	
$CMRR$	Common Mode Rejection Ratio	DC, $V_{CM} = 0\text{V}$ to $(V_{CC}-1.5)\text{V}$	60	70	—	dB
			60	—	—	
$PSRR$	Power Supply Rejection Ratio	$V_{CC} = 5\text{V}$ to $30\text{V}$	70	100	—	dB
			60	—	—	
$CS$	Channel Separation	$f = 1\text{kHz}$ to $20\text{kHz}$	—	-120	—	dB
$I_{SOURCE}$	Source	$V_{IN+} = 1\text{V}$ , $V_{IN-} = 0\text{V}$ , $V_{CC} = 15\text{V}$ , $V_O = 2\text{V}$	20	40	—	mA
		—	20	—	—	
$I_{SINK}$	Sink	$V_{IN+} = 0\text{V}$ , $V_{IN-} = 1\text{V}$ , $V_{CC} = 15\text{V}$ , $V_O = 2\text{V}$	10	15	—	mA
		—	5	—	—	
		$V_{IN+} = 0\text{V}$ , $V_{IN-} = 1\text{V}$ , $V_{CC} = 15\text{V}$ , $V_O = 0.2\text{V}$	12	50	—	$\mu\text{A}$
$I_{SC}$	Output Short Circuit Current to Ground	$V_{CC} = 15\text{V}$	—	40	60	mA
$V_{OH}$	Output Voltage Swing	$V_{CC} = 30\text{V}$ , $R_L = 2\text{k}\Omega$	26	—	—	V
		—	26	—	—	
$V_{OL}$		$V_{CC} = 30\text{V}$ , $R_L = 10\text{k}\Omega$	27	28	—	mV
		—	27	—	—	
$\theta_{JC}$	Thermal Resistance (Junction to Case)	$V_{CC} = 5\text{V}$ , $R_L = 10\text{k}\Omega$	—	5	20	mV
			—	—	30	
$\theta_{JA}$	Thermal Resistance (Junction to Ambient)		—	17	—	$^\circ\text{C}/\text{W}$
			—	115	—	

Notes: 1. Limits over the full temperature are guaranteed by design, but not tested in production.

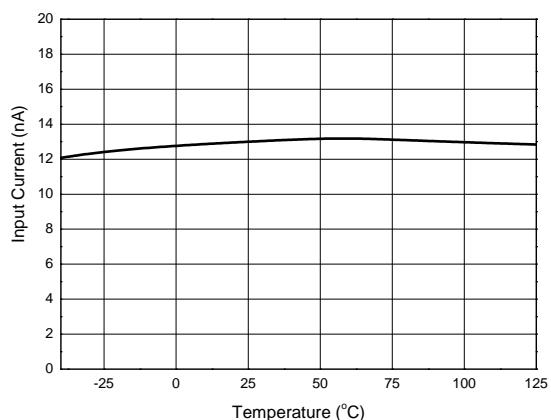
2. The input common-mode voltage of either input signal voltage should not be allowed to go negatively by more than  $0.3\text{V}$  (at  $+25^\circ\text{C}$ ). The upper end of the common-mode voltage range is  $V_{CC}-1.5\text{V}$  (at  $+25^\circ\text{C}$ ), but either or both inputs can go to  $+36\text{V}$  without damages, independent of the magnitude of the  $V_{CC}$ .

## Performance Characteristics

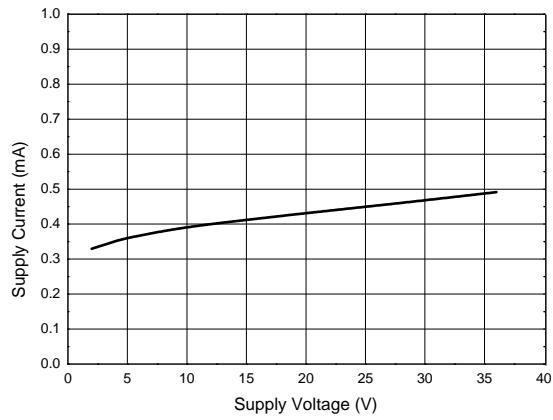
**Input Voltage Range**



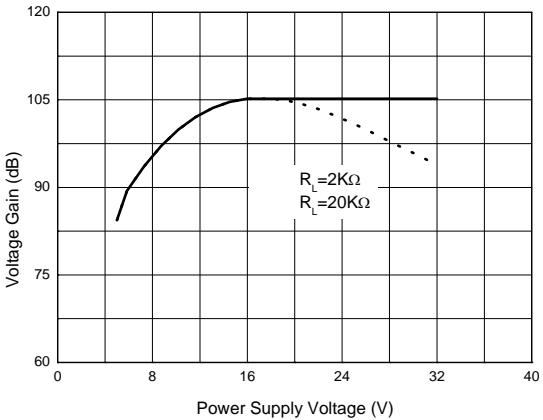
**Input Current**



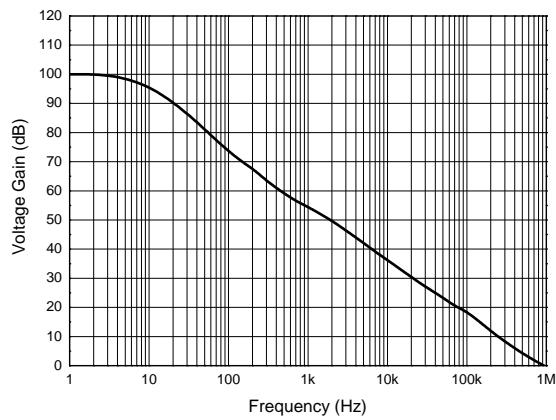
**Supply Current**



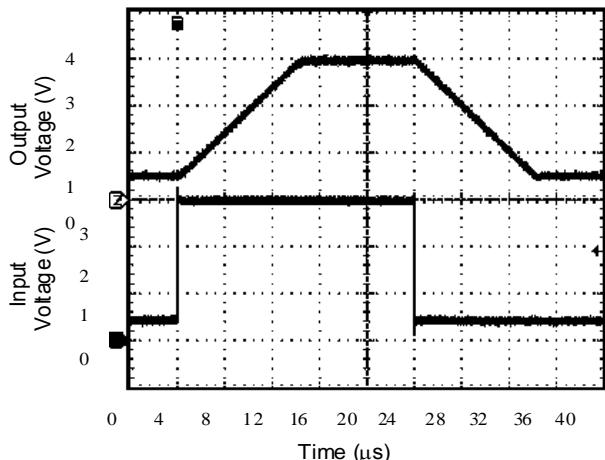
**Voltage Gain**



**Open Loop Frequency Response**

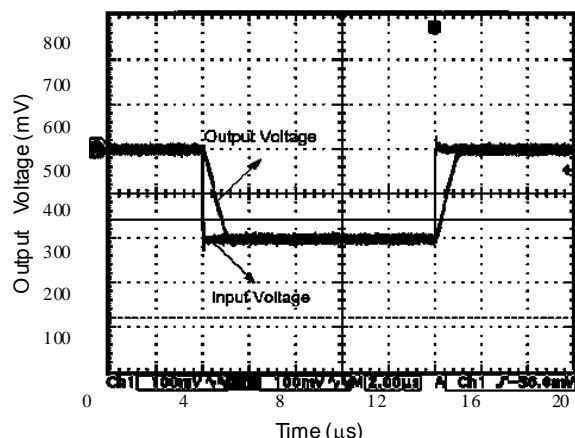


**Voltage Follower Pulse Response**

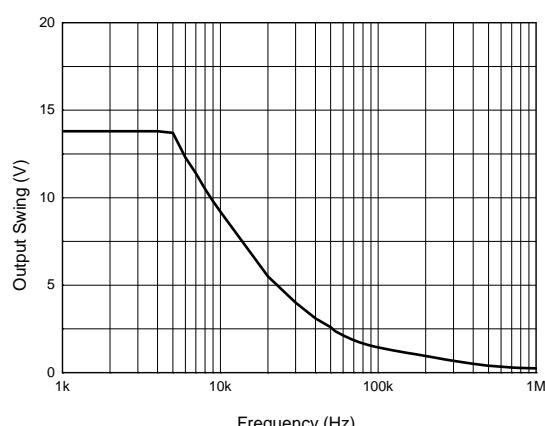


**Performance Characteristics (Cont.)**

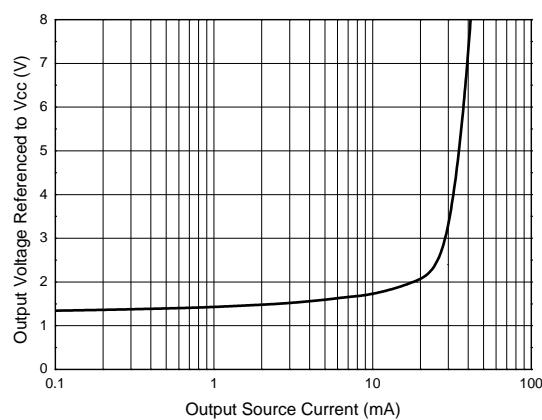
**Voltage Follower Pulse Response (Small Signal)**



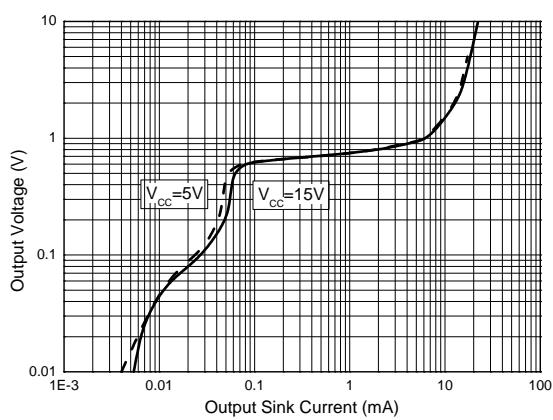
**Large Signal Frequency Response**



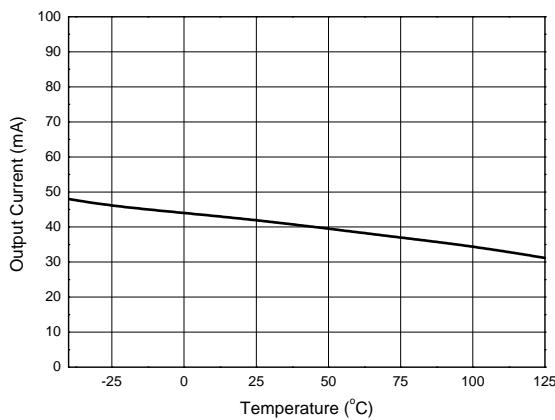
**Output Characteristics: Current Sourcing**



**Output Characteristics: Current Sinking**

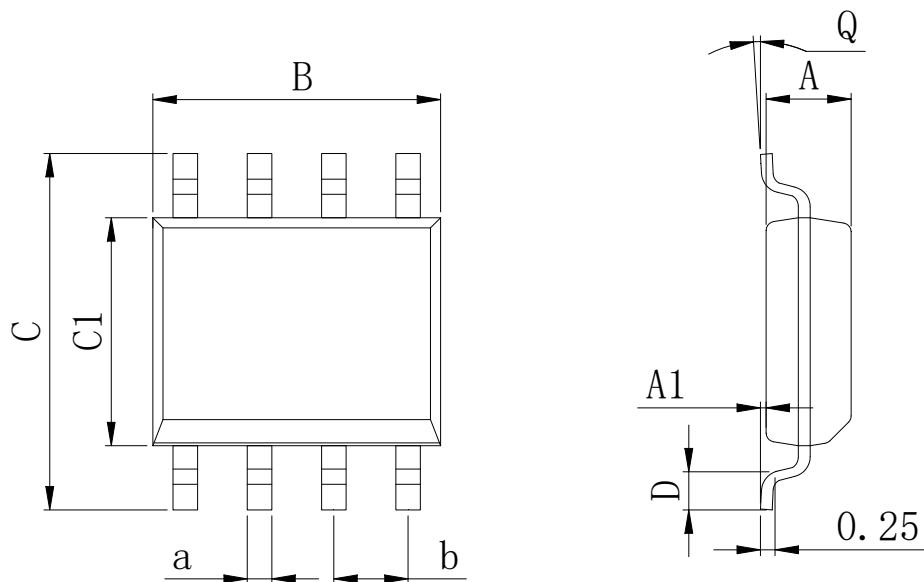


**Current Limiting**



## Physical Dimensions

SOP-8



Dimensions In Millimeters(SOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	9.620	4.00	0.80	8°	0.45	

## ORDER INFORMATION

P/N	PKG	QTY
LM358ADT-MS	SOP-8	2500

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